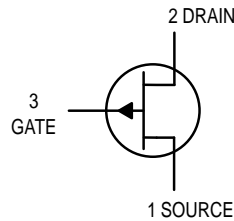
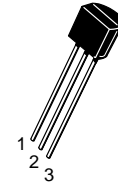


JFET Amplifiers

P-Channel — Depletion



**2N5460
thru
2N5462**



**CASE 29-04, STYLE 7
TO-92 (TO-226AA)**

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain–Gate Voltage	V_{DG}	40	Vdc
Reverse Gate–Source Voltage	V_{GSR}	40	Vdc
Forward Gate Current	$I_G(f)$	10	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/°C
Junction Temperature Range	T_J	–65 to +135	°C
Storage Channel Temperature Range	T_{stg}	–65 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Gate–Source Breakdown Voltage ($I_G = 10 \mu\text{Adc}$, $V_{DS} = 0$)	2N5460, 2N5461, 2N5462	$V_{(BR)GSS}$	40	—	—	Vdc
Gate Reverse Current ($V_{GS} = 20 \text{ Vdc}$, $V_{DS} = 0$)	2N5460, 2N5461, 2N5462	I_{GSS}	—	—	5.0	nAdc
($V_{GS} = 30 \text{ Vdc}$, $V_{DS} = 0$)	2N5460, 2N5461, 2N5462		—	—	1.0	μAdc
($V_{GS} = 20 \text{ Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)	2N5460, 2N5461, 2N5462		—	—	1.0	μAdc
($V_{GS} = 30 \text{ Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)	2N5460, 2N5461, 2N5462		—	—	1.0	μAdc
Gate–Source Cutoff Voltage ($V_{DS} = 15 \text{ Vdc}$, $I_D = 1.0 \mu\text{Adc}$)	2N5460 2N5461 2N5462	$V_{GS(off)}$	0.75 1.0 1.8	— — —	6.0 7.5 9.0	Vdc
Gate–Source Voltage ($V_{DS} = 15 \text{ Vdc}$, $I_D = 0.1 \text{ mAdc}$)	2N5460	V_{GS}	0.5	—	4.0	Vdc
($V_{DS} = 15 \text{ Vdc}$, $I_D = 0.2 \text{ mAdc}$)	2N5461		0.8	—	4.5	Vdc
($V_{DS} = 15 \text{ Vdc}$, $I_D = 0.4 \text{ mAdc}$)	2N5462		1.5	—	6.0	Vdc

ON CHARACTERISTICS

Zero–Gate–Voltage Drain Current ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{ kHz}$)	2N5460 2N5461 2N5462	I_{DSS}	–1.0 –2.0 –4.0	— — —	–5.0 –9.0 –16	mAdc
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SMALL-SIGNAL CHARACTERISTICS

Forward Transfer Admittance ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{ kHz}$)	2N5460 2N5461 2N5462	$ y_{fs} $	1000 1500 2000	— — —	4000 5000 6000	μmhos
Output Admittance ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{ kHz}$)		$ y_{os} $	—	—	75	μmhos
Input Capacitance ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{ MHz}$)		C_{iss}	—	5.0	7.0	pF
Reverse Transfer Capacitance ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 1.0 \text{ MHz}$)		C_{rss}	—	1.0	2.0	pF

FUNCTIONAL CHARACTERISTICS

Noise Figure ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $R_G = 1.0 \text{ Megohm}$, $f = 100 \text{ Hz}$, $BW = 1.0 \text{ Hz}$)		NF	—	1.0	2.5	dB
Equivalent Short–Circuit Input Noise Voltage ($V_{DS} = 15 \text{ Vdc}$, $V_{GS} = 0$, $f = 100 \text{ Hz}$, $BW = 1.0 \text{ Hz}$)		e_n	—	60	115	$\text{nV}/\sqrt{\text{Hz}}$



DRAIN CURRENT versus GATE SOURCE VOLTAGE

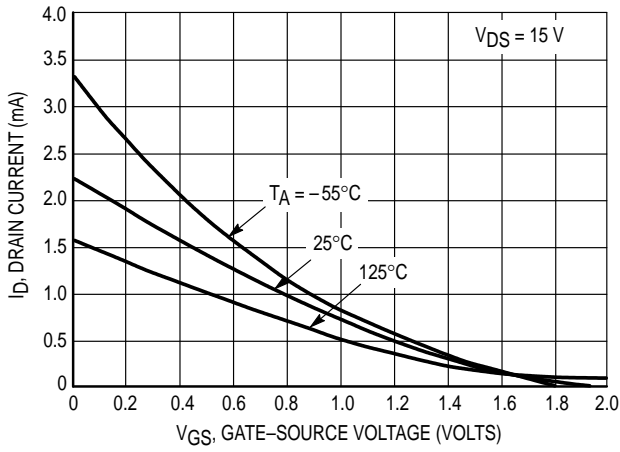


Figure 1. $V_{GS(off)} = 2.0$ Volts

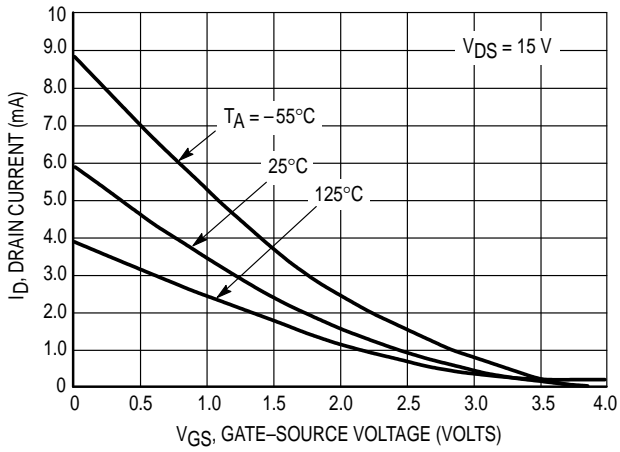


Figure 2. $V_{GS(off)} = 4.0$ Volts

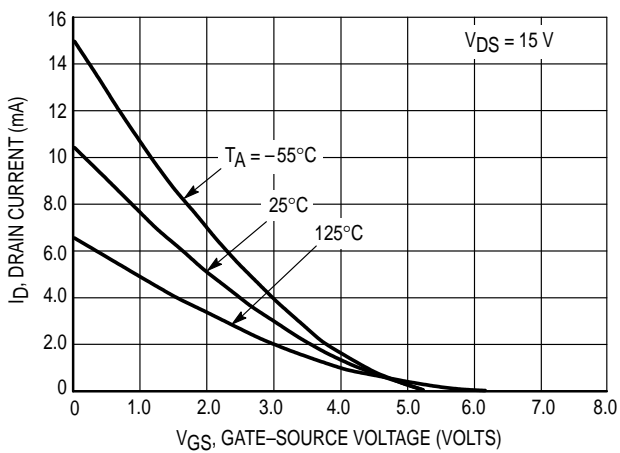


Figure 3. $V_{GS(off)} = 5.0$ Volts

FORWARD TRANSFER ADMITTANCE versus DRAIN CURRENT

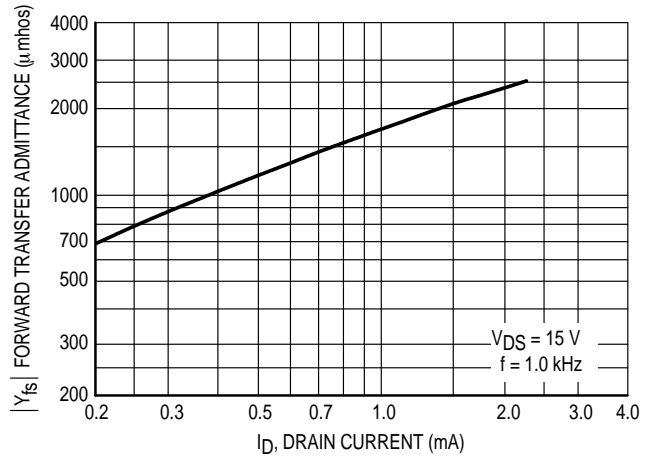


Figure 4. $V_{GS(off)} = 2.0$ Volts

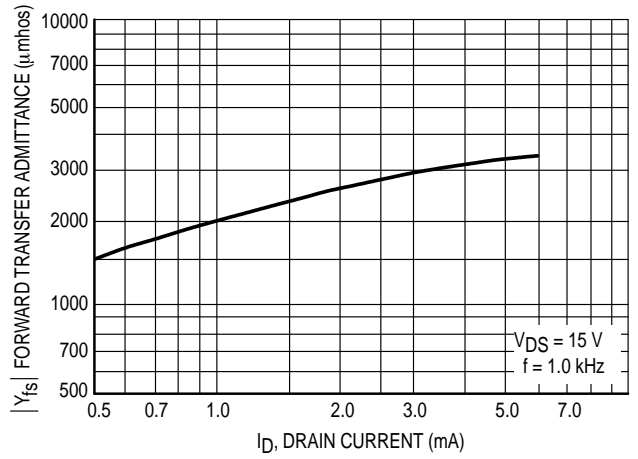


Figure 5. $V_{GS(off)} = 4.0$ Volts

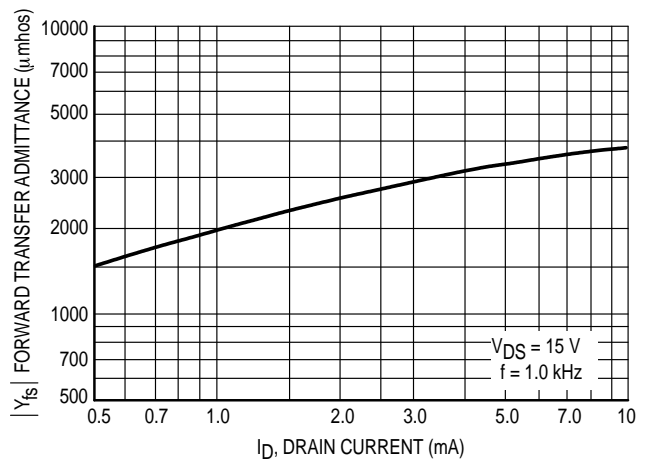


Figure 6. $V_{GS(off)} = 5.0$ Volts

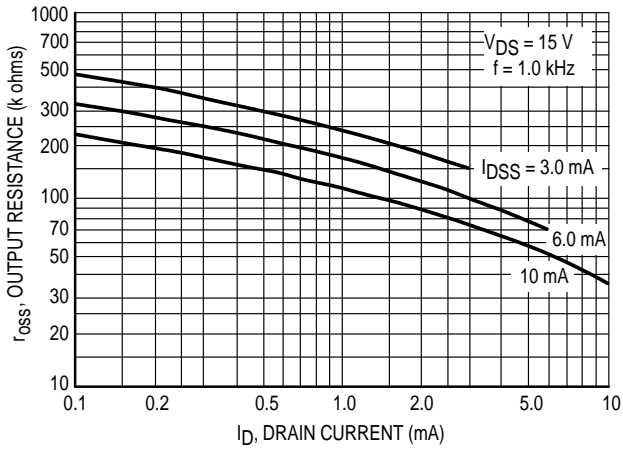


Figure 7. Output Resistance versus Drain Current

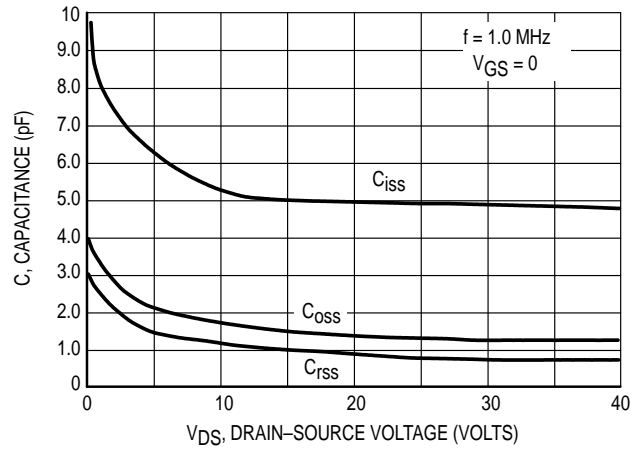


Figure 8. Capacitance versus Drain-Source Voltage

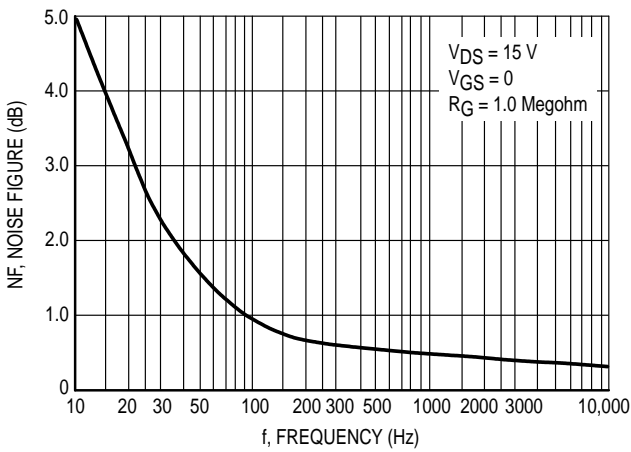


Figure 9. Noise Figure versus Frequency

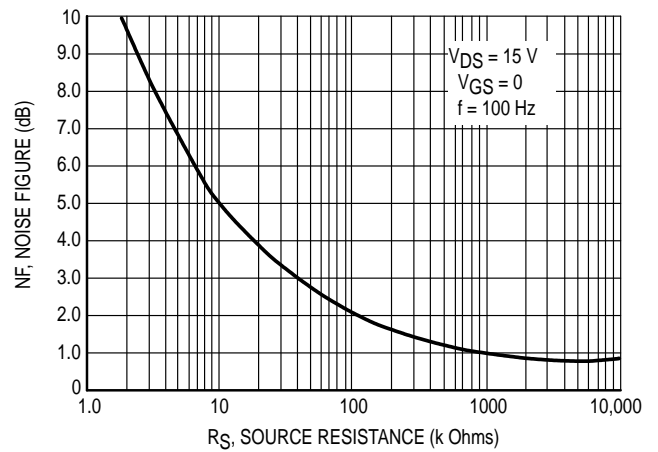
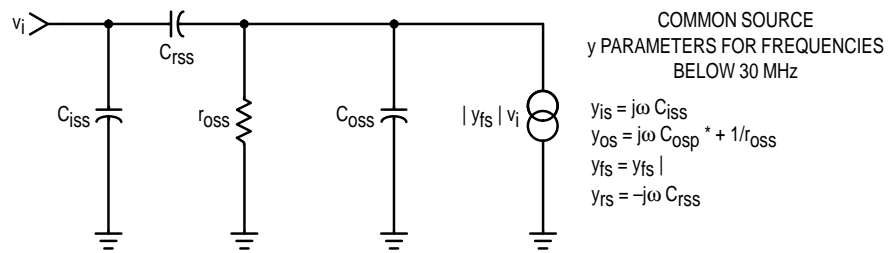


Figure 10. Noise Figure versus Source Resistance



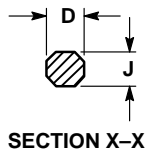
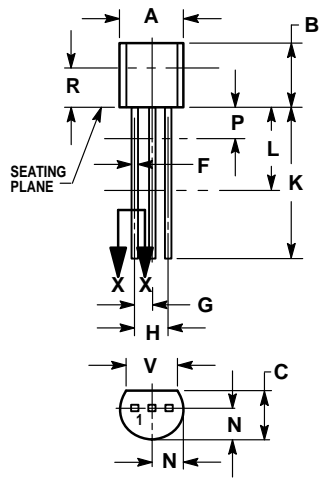
* C_{osp} is C_{oss} in parallel with Series Combination of C_{iss} and C_{rss} .

NOTE:

- Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%).

Figure 11. Equivalent Low Frequency Circuit

PACKAGE DIMENSIONS



CASE 029-04
(TO-226AA)
ISSUE AD

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

STYLE 7:

1. SOURCE
2. DRAIN
3. GATE

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